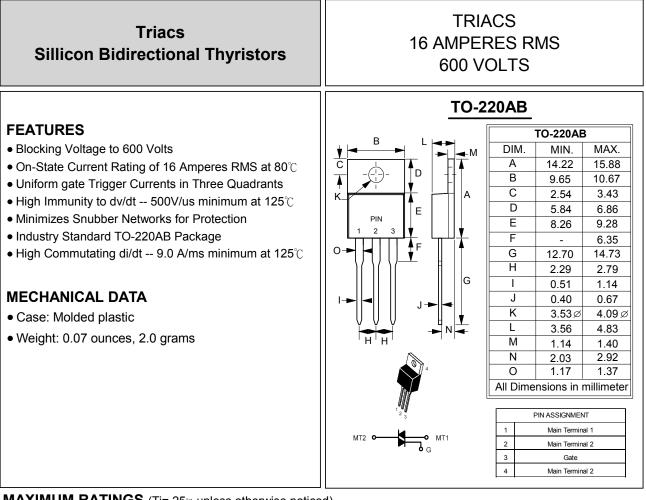
# LITE ON SEMICONDUCTOR

## T16M50T600B



#### MAXIMUM RATINGS (Tj= 25°C unless otherwise noticed)

Rating		Value	Unit
Peak Repetitive Off– State Voltage (1) (TJ= -40 to 125℃, Sine Wave, 50 to 60 Hz; Gate Open)	Vdrm, Vrrm	600	Volts
On-State RMS Current (Tc = +80℃) Full Cycle Sine Wave 50 to 60 Hz		16	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, TJ= +125°C)		150	Amps
Circuit Fusing Consideration (t = 8.3 ms)		93	A <sup>2</sup> s
k Gate Power (Tc = +80°C, Tp $\leq$ 1.0 us) PGM		20	Watts
Average Gate Power (Tc = +80°C, t=8.3 ms)	PG(AV)	0.5	Watts
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	Tstg	-40 to +150	°C
Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking REV. 3,Oct-2010, KT			

voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

#### THERMAL CHARACTERISTICS

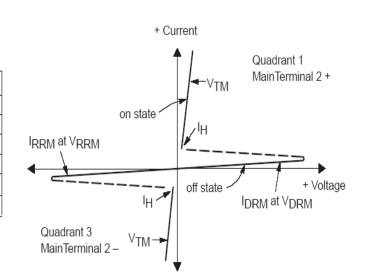
Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction to Case - Junction to Ambient	RthJC RthJA	2.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T∟	260	°C

#### **ELECTRICAL CHARACTERISTICS** (TJ=25°C unless otherwise noted, Electrical apply in both directions)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			1	1	
Peak Reptitive Forward or Reverse Blocking Current TJ=25°C (VD=Rated VDRM, VRRM; Gate Open) TJ=125°C	IDRM IRRM			10 2.0	uA mA
ON CHARACTERISTICS					
Peak On-State Voltage (ITM=± 21 A Peak @Tp $\leq$ 2.0 ms, Duty Cycle $\leq$ 2%)	Vtm		1.2	1.6	Volts
Gate Trigger Current (VD = 12Vdc; RL = 100 Ohms)	lgt1 lgt2 lgt3	10 10 10		50 50 50	mA
Gate Trigger Voltage (VD = 12 Vdc; RL =100 Ohms)	VGT1 VGT2 VGT3	0.5 0.5 0.5		1.5 1.5 1.5	Volts
Holding Current (V <sub>D</sub> = 12 V, Initiating Current = $\pm$ 150 mA, Gate Open)	Ін			50	mA
Latching Current (VD = 24 V, IG = 50 mA)	ΙL			50 80 50	mA

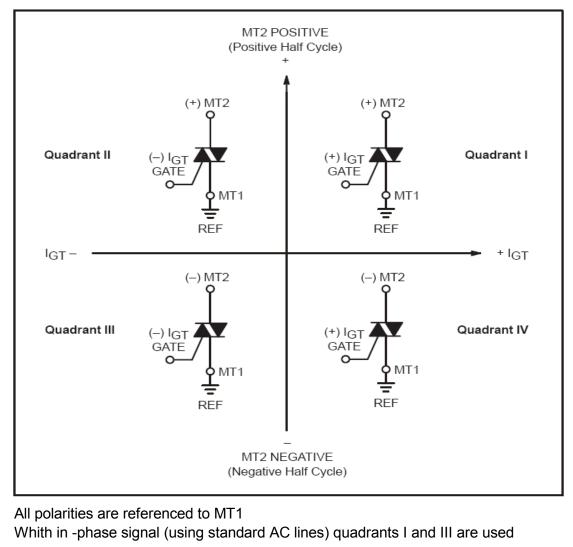
#### DYNAMIC CHARACTERISTICS

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
ΙΗ	Holding Current

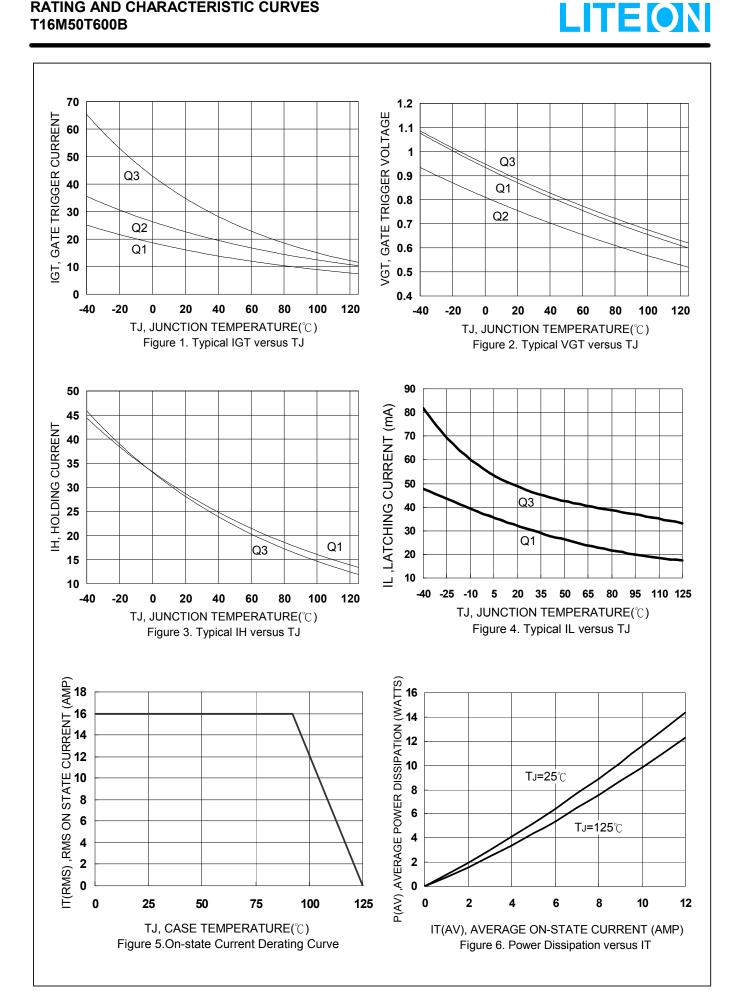


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### **Quadrant Definitions**

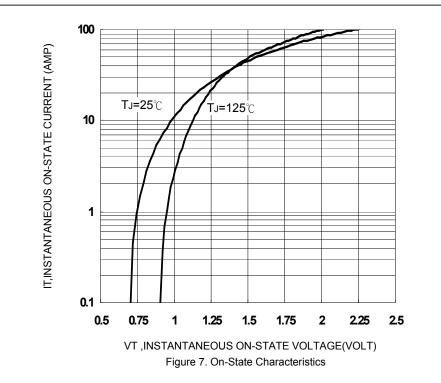


#### **RATING AND CHARACTERISTIC CURVES** T16M50T600B



## RATING AND CHARACTERISTIC CURVES T16M50T600B







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